Claims:

1. An apparatus for processing substrates, comprising:

a) a transfer chamber;

one or more load lock chambers connected to the transfer chamber;

one or more process chambers connected to the transfer chamber;

d) a modular plumbing tray disposed adjacent the transfer chamber and having facility connections for one or more of the process chambers and the load lock chambers; and

e) a chamber tray disposed adjacent the one or more of the process 9 chambers, load lock chambers and transfer chamber, the chamber tray having facility 10 connections connected to one or more facility connections in the plumbing tray.

1 \ 2. A method of processing a substrate, comprising:

a) introducing a substrate into a load lock chamber from atmospheric

3 pressure;

degassing and/or pre-heating the substrate in the load lock chamber;

5 c) introducing the substrate into a transfer chamber; and

d) processing the substrate in one or more process chambers.

1 *3. The method of claim 2 further comprising:

e) introducing the substrate into the load lock chamber;

g cooling the substrate in the load lock chamber; and then

4 g) venting the load lock chamber to atmospheric pressure.

1 4. An apparatus for distributing facility to devices on a processing system,

2 comprising:

a) an enclosure having at least one facility interface and one or more

4 chamber interfaces; and



- b) one or more of a process gas manifold, vacuum manifold, water manifold and a helium manifold disposed in the enclosure connected between the at least one facility interface and the one or more chamber interfaces.
- 1 5. An apparatus for distributing facility, comprising:
- 2 a) a support frame having one or more of an electronics box, a gas panel, a vacuum line and a controller device disposed thereon.
- 1 6. A method of processing substrates, comprising:
- 2 a) positioning a pair of substrates on two blades on separate robots in a 3 processing system;
- b) moving the substrates in parallel to a pair of first process chambers; and then
- 6 c) moving the substrates in parallel to a pair of second process chambers.